

MMBF170

N-Channel Enhancement Mode MOSFET

Features

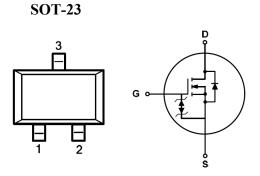
- Surface-mounted package
- Advanced trench cell design
- Extremely low threshold voltage
- ESD protected (HBM > 2KV)

Quick reference

- BV \geq 60 V
- $P_{tot} \leq 0.83 \text{ W}$
- ID $\leq 0.5 \text{ A}$

Limiting Values

- $R_{DS(ON)} \leq 3 \Omega @ V_{GS} = 10 V$
- $R_{DS(ON)} \leq 4 \Omega (a) V_{GS} = 4.5 V$



Top View 1 :Gate(G) 2 :Source(S) 3 :Drain(D)

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	Drain-Source Voltage	T _A = 25 °C	-	60	V
V _{GS}	Gate-Source Voltage	T _A = 25 °C	-	± 20	V
I _D *	Drain Current	T _A = 25 °C, V _{GS} = 10 V	-	0.5	А
I _{DM} ***	Pulsed Drain Current	T _A = 25 °C, V _{GS} = 10 V	-	1.7	А
P _{tot} *	Total Power Dissipation	T _A = 25 °C	-	0.83	W
		T _A = 100 °C	-	0.33	
T _{stg}	Storage Temperature		- 55	150	°C
TJ	Junction Temperature		-	150	°C
I _S *	Diode Forward Current	T _A = 25 °C	-	0.4	А
R _{eja} *	Thermal Resistance- Junction to Ambient			150	°C / W

Notes : * Surface Mounted on 1 in 2 pad area, $t \le 10$ sec

** Pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %







Electrical Characteristics (TA = 25 °C Unless Otherwise Noted)

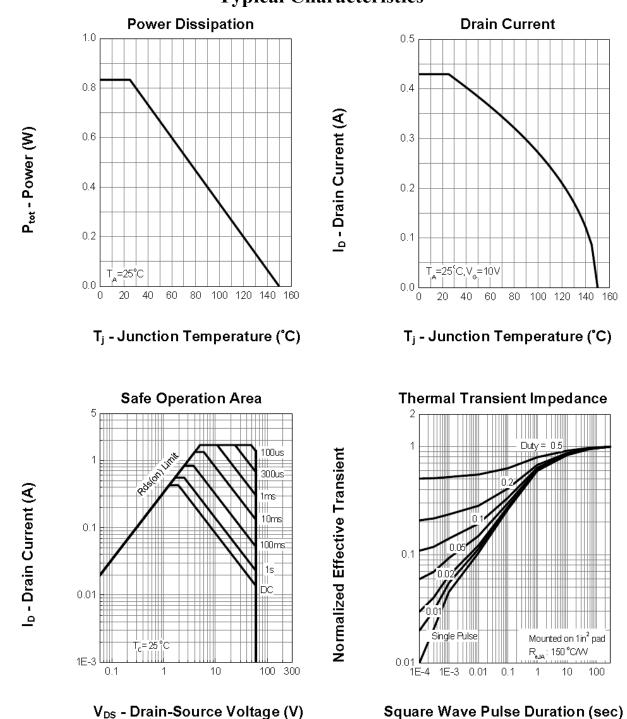
Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Static Characteristics									
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0 V, I _{DS} = 250 µA		60	-	-	V		
V _{GS(th)}	Gate Threshold Voltage	V_{DS} = V_{GS} , I_{DS} = 250 μ A		1.0	1.6	2.5	V		
I _{DSS}	Drain Leakage Current	V _{DS} = 48 V, V _{GS} = 0 V		-	-	1	μA		
			T _J = 85 ℃	-	-	30	μA		
I _{GSS}	Gate Leakage Current	V_{GS} = ± 20 V, V_{DS}	s = 0 V	-	-	± 10	μA		
Б а		V _{GS} = 10 V, I _{DS} = 0.4 A			1.9	3.0	Ω		
R _{DS(ON)} ^a	On-State Resistance	V _{GS} = 4.5 V, I _{DS} = 0.3 A		-	2.4	4.0			
Diode Characteristics									
V _{SD} ^a	Diode Forward Voltage	I _{SD} = 0.4 A, V _{GS} = 0 V		-	0.7	1.3	V		
t _{rr}	Reverse Recovery Time	I _{SD} = 0.4 A, dI _{SD} / dt = 100 A / μs		-	40	-	ns		
Q _{rr}	Reverse Recovery Charge			-	40	-	nC		
Dynamic Characteristics ^b									
R _G	Gate Resistance	$V_{GS} = V_{DS} = 0 V,$	F = 1 MHz	_	130	-	Ω		
C _{iss}	Input Capacitance	V _{GS} = 0 V, V _{DS} = 25 V Frequency = 1 MHz		-	30	-			
C _{oss}	Output Capacitance			-	4.2	-	pF		
C _{rss}	Reverse Transfer Capacitance			-	3	-			
t _d (on)	Turn-on Delay Time	$V_{DS} = 30 V, V_{GEN} = 10 V,$ $R_G = 25 \Omega, R_L = 150 \Omega,$ $I_{DS} = 0.2 A$		-	3.9	9			
t _r	Turn-on Rise Time			-	3.5	8			
t _d (off)	Turn-off Delay Time			-	16	40	ns		
t _f	Turn-off Fall Time			-	10	20			
		·							
Qg	Total Gate Charge	$V_{GS} = 4.5 V, V_{DS} = 10 V,$ $I_{DS} = 0.4 A$		-	305	-			
Q _{gs}	Gate-Source Charge			-	85	-	рС		
Q _{gd}	Gate-Drain Charge			-	205	-			

Notes : a : Pulse test ; pulse width \leq 300 µs, duty cycle \leq 2 % b : Guaranteed by design, not subject to production testing







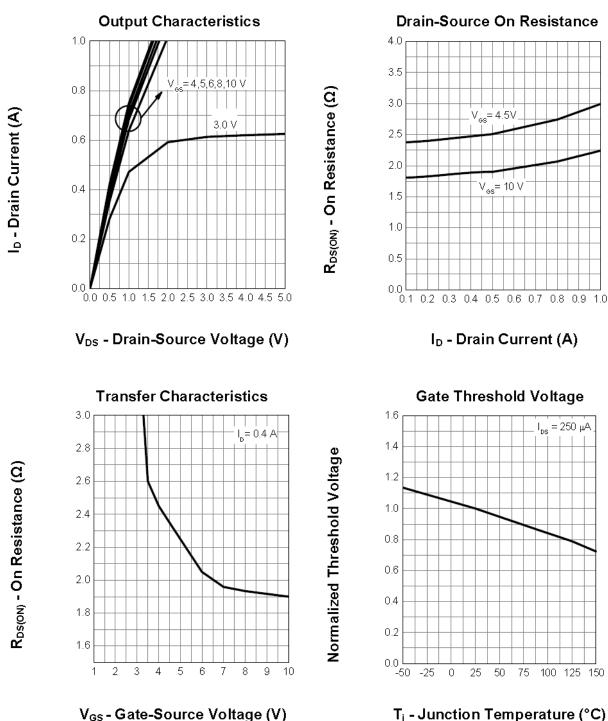


Typical Characteristics





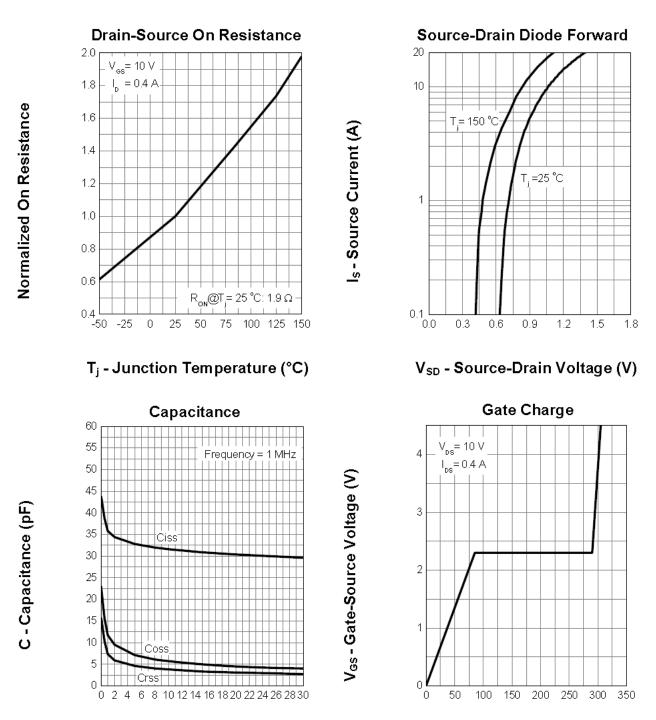




T_i - Junction Temperature (°C)







V_{DS} - Drain-Source Voltage (V)

Q_G - Gate Charge (pC)

MMBF170

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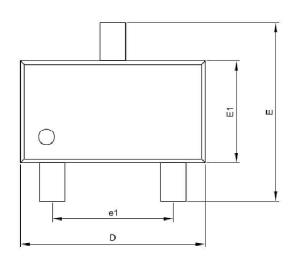


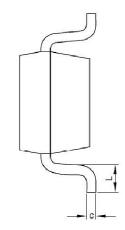


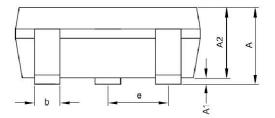


Package Dimensions

SOT-23







Symbol	Dimensions In Millimeters		
Symbol	MIN.	MAX.	
A		1.12	
A1	0.00	0.1	
A2	0.90	1.02	
D	2.90 BSC		
E	2.40 BSC		
E1	1.20	1.40	
с	0.08	0.25	
b	0.30	0.50	
е	0.95 BSC		
e1	1.90 BSC		
L	0.20	0.60	



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